

# SANYO Semiconductors DATA SHEET

# STK416-100-E 3-Channel Power Switching Audio Power IC, 90W×3ch

#### Overview

The STK416-100-E is a class H audio power amplifier hybrid IC that features a built-in power supply switching circuit. This IC provides high efficiency audio power amplification by controlling (switching) the supply voltage supplied to the power devices according to the detected level of the input audio signal.

# **Applications**

• Audio power amplifiers.

### **Features**

- Pin-to-pin compatible outputs ranging from 90W to 150W.
- Can be used to replace the STK415-100 series and the class-AB series (2, 3-channel models) due to its pin compatibility.
- Pure complementary construction by new Darlington power transistors
- Output load impedance:  $R_L = 8\Omega$  to  $4\Omega$  supported

# **Series Models**

	STK416-100-E	STK416-120-E	STK416-130-E					
Output 1 (10%/1kHz)	90W×3ch	120W×3ch	150W×3ch					
Output 2 (0.8%/20Hz to 20kHz)	60W×3ch	80W×3ch	100W×3ch					
Max. rated V <sub>H</sub> (no sig.)	±65V	±73V	±80V					
Max. rated V <sub>L</sub> (no sig.)	±42V	±45V	±46V					
Recommended operating $V_H$ (8 $\Omega$ )	±39V	±46V	±51V					
Recommended operating $V_L$ (8 $\Omega$ )	±29V	±32V	±34V					
Dimensions (excluding pin height)		78.0mm×44.1mm×9.0mm						

- Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application", intended for the use as general electronics equipment (home appliances, AV equipment, communication device, office equipment, industrial equipment etc.). The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for applications outside the standard applications of our customer who is considering such use and/or outside the scope of our intended standard applications, please consult with us prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.
- Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

# **Specifications**

**Absolute maximum ratings** at Ta=25°C (excluding rated temperature items), Tc=25°C unless otherwise specified

Parameter	Symbol	Conditions	Ratings	Unit
V <sub>H</sub> maximum quiescent supply voltage 1	V <sub>H</sub> max (1)	When no signal	±65	V
V <sub>H</sub> maximum supply voltage 2	V <sub>H</sub> max (2)	R <sub>L</sub> ≥6Ω	±57	V
V <sub>H</sub> maximum supply voltage 3	V <sub>H</sub> max (3)	R <sub>L</sub> ≥4Ω	±46	V
V <sub>L</sub> maximum quiescent supply voltage 1	V <sub>L</sub> max (1)	When no signal	±42	V
V <sub>L</sub> maximum supply voltage 2	V <sub>L</sub> max (2)	R <sub>L</sub> ≥6Ω	±37	V
V <sub>L</sub> maximum supply voltage 3	V <sub>L</sub> max (3)	R <sub>L</sub> ≥4Ω	±29	V
Maximum voltage between V <sub>H and</sub> V <sub>L</sub> *4	V <sub>H</sub> -V <sub>L</sub> max	No loading	60	V
Standby pin maximum voltage	Vst max		-0.3 to +5.5	V
Thermal resistance	θј-с	Per power transistor	1.8	°C/W
Junction temperature	Tj max	Both the Tj max and Tc max conditions must be met.	150	°C
IC substrate operating temperature	Tc max		125	°C
Storage temperature	Tstg		-30 to +125	°C
Allowable load shorted time *3	ts	$V_H$ =±39V, $V_L$ =±29V, $R_L$ =8 $\Omega$ , f=50Hz, $P_O$ =60W, 1-channel active	0.3	s

#### Electrical Characteristics at Tc=25°C, RL=8Ω (non-inductive load), Rg=600Ω, VG=40dB, VZ=15V

				Cond								
Parameter	Symbol		V (V)	f (Hz)	P <sub>O</sub> (W)	THD (%)		min	typ	max	unit	
Output power	P <sub>O</sub> (1)	V <sub>H</sub> V <sub>L</sub>	±39 ±29	20 to 20k		0.8		60				
	P <sub>O</sub> (2)	V <sub>H</sub> V <sub>L</sub>	±32 ±24	1k		0.8	R <sub>L</sub> =4Ω		60		W	
Total harmonic distortion	THD	V <sub>H</sub> V <sub>L</sub>	±39 ±29	20 to 20k	60				0.4		%	
Frequency characteristics	fL, fH	V <sub>H</sub> V <sub>L</sub>	±39 ±29		1.0	1.0 +0 -3dB			20 to 50	<	Hz	
Input impedance	ri	V <sub>H</sub> V <sub>L</sub>	±39 ±29	1k	1.0				55		kΩ	
Output noise voltage *2	V <sub>NO</sub>	V <sub>H</sub> V <sub>L</sub>	±47 ±31				Rg=2.2kΩ			1.0	mVrms	
Quiescent current	Icco	٧ <sub>H</sub>	±47				R <sub>I</sub> =∞			40	mA	
		٧L	±31				KĽ-∞			150	IIIA	
Output neutral voltage	VN	V <sub>H</sub> V <sub>L</sub>	±47 ±31					-70	0	+70	mV	
Pin 17 voltage when standby ON *7	VST ON	V <sub>H</sub> V <sub>L</sub>	±39 ±29				Standby		0	0.6	V	
Pin 17 voltage when standby OFF *7	VST OFF	V <sub>H</sub> V <sub>L</sub>	±39 ±29				Operating	2.5	3.0		V	

#### [Remarks]

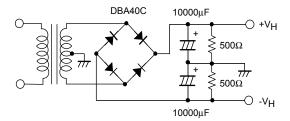
- \*1: Unless otherwise specified, use a constant-voltage power supply to supply power when inspections are carried out.
- \*2: The output noise voltage values shown are peak values read with a VTVM. However, an AC stabilized (50Hz) power supply should be used to minimize the influence of AC primary side flicker noise on the reading.
- \*3: Use the designated transformer power supply circuit shown in the figure below for the measurements of allowable load shorted time and output noise voltage.
- \*4: Design circuits so that  $(|V_H|-|V_L|)$  is always less than 40V when switching the power supply with the load connected.
- \*5: Set up the V<sub>L</sub> power supply with an offset voltage at power supply switching (V<sub>L</sub>-V<sub>O</sub>) of about 8V as an initial target.
- \*6: Please connect –Pre V<sub>CC</sub> pin (#5 pin) with the stable minimum voltage and connect so that current does not flow in by reverse bias.
- \*7: Use the standby pin (pin 17) so that the applied voltage never exceeds the maximum rating. The power amplifier is turned on by applying +2.5V to +5.5V to the standby pin (pin 17).

Continued on next page.

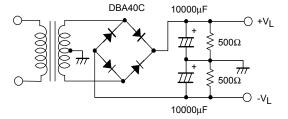
Continued from preceding page.

- \*8: Thermal design must be implemented based on the conditions under which the customer's end products are expected to operate on the market.
- \*9: The thermoplastic adhesive is used to bond the case and the aluminum substrate, so, please be sure to fix the Hybrid IC on the heat sink before soldering and mount it. In addition, please attach and remove the heat sink at normal temperature.
- \*10: Weight of HIC: 36.8g

Outer carton dimensions (W×L×H): 452mm×325mm×192mm



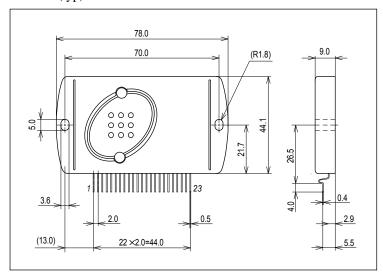
Designated transformer power supply (MG-250 equivalent)



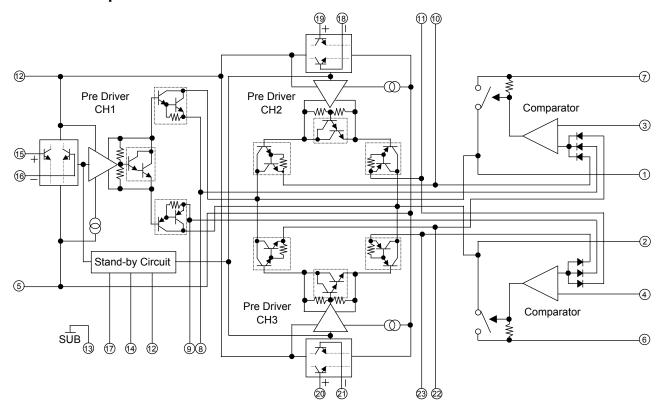
Designated transformer power supply (MG-200 equivalent)

# **Package Dimensions**

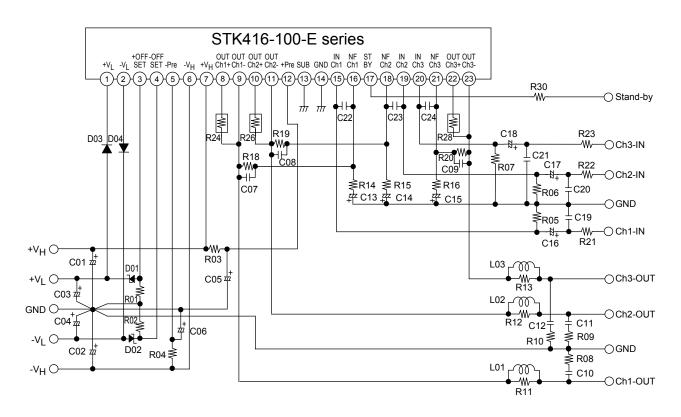
unit:mm (typ)



# **Internal Equivalent Circuit**



# **Test Circuit**

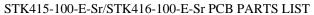


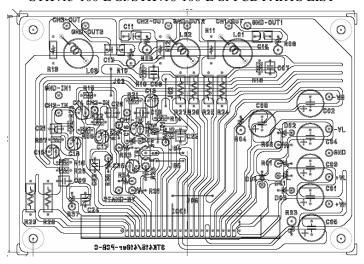


# **Recommended External Components**

Parts Location	Recommended Value	Circuit Purpose	Above Recommended Value	Below Recommended Value
R01, R02	1.5kΩ	Current for supply switch circuit (comparator) is determined.	V <sub>H</sub> holding frequency range becomes large.	V <sub>H</sub> holding frequency range becomes narrow.
R03, R04	100Ω/1W	Resistance for ripple filter. (Fuse resistance is recommended. Ripple filter is constituted with C05, C06.)	Short-through current may decrease at high frequency.	Short-through current may increase at high frequency.
R05, R06, R07	56kΩ	Input impedance is determined.	Output neutral voltage (VN) (It is referred that R05=R18	
R08, R09, R10	4.7Ω/1W	Resistance for oscillation prevention.	-	-
R11, R12, R13	4.7Ω	Noise absorption resistance.	-	-
R14, R15, R16	560Ω	Voltage gain (VG) is determined with R18, R19, R20. (As for VG, it is desirable to set up by R14, R15, R16.)	It may oscillate. (VG<40dB)	With especially no problem
R18, R19, R20	56kΩ	Voltage gain (VG) is determined with R14, R15, R16	-	-
R21, R22, R23	1kΩ	Resistance for input filters.	-	-
R24, R26, R28	0.22Ω ±10%, 5W	Output emitter resistor (Metal-plate Resistor is recommended.)	Decrease of maximum output power	It may cause thrmal runaway
R30	Note*7	Select restriction resistance, for the impression voltage rating.	e of '#17 (stand-by) pin' mus	t not exceed the maximum
C01, C02	100μF/100V	Capacitor for oscillation prevention.  •Locate near the HIC as much as possible.  •Power supply impedance is lowered and stable operation of the IC is carried out.  (Electrolytic capacitor is recommended.)	-	-
C03, C04	100μF/50V	Capacitor for oscillation prevention.  •Locate near the HIC as much as possible.  •Power supply impedance is lowered and stable operation of the IC is carried out.  (Electrolytic capacitor is recommended.)	-	-
C05, C06	100μF/100V	Decoupling capacitor     The ripple ingredient mixed in an input side is removed from a power supply line.     (Ripple filter is constituted with R03, R04.)	The change in the ripple ing side from a power supply lin	·
C07, C08, C09	3pF	Capacitor for oscillation prevention.	It may oscillate.	
C10, C11, C12	0.1μF	Capacitor for oscillation prevention.	It may oscillate.	
C13, C14, C15	22μF/10V	Negative feedback capacitor.  •The cutoff frequency of a low cycle changes.  (f <sub>L</sub> =1/(2π•C13•R14))	The voltage gain (VG) of low frequency is extended. However, the pop noise at the time of a power supply injection also becomes large.	The voltage gain (VG) of low frequency decreases.
C16, C17, C18	2.2μF/50V	Input coupling capacitor (for DC current prevention.)	-	=
C19, C20, C21	470pF	Input filter capacitor  •A high frequency noise is reduced with the filter constituted by R21, R22, R23.	-	-
C22, C23, C24	100pF	Capacitor for oscillation prevention.	It may oscillate.	
D01, D02	15V	Decide offset voltage for supply voltage ciecuit.	Decrease distortion at supply voltage shift	Increase distortion at supply voltage shift
D03, D04	3A/60V	Adverse current prevention diode (FRD is recommended)	-	-
L01, L02, L03	ЗμН	Coil for oscillation prevention.	With especially no problem	It may oscillate.

# **Sample PCB Trace Pattern**





# STK415, 416-100-E Series PCB Parts List

PCB Name: STK415/416sr-PCB C

Location (*2) 2ch Amp doesn't n		PARTS	RATING	Component				
R01, R02		ERG1SJ152	1.5kΩ, 1W	0				
R03, R04		ERG1SJ101	100Ω, 1W	0				
R05, R06, (R07), R18, R19, (	R20)	RN16S563FK	56kΩ, 1/6W	0				
R08, R09, (R10)		ERX1SJ4R7	4.7Ω, 1W	0				
R11, R12, (R13)		RN14S4R7FK	4.7Ω, 1/4W	0				
R14, R15, (R16)		RN16S561FK	560Ω, 1/6W	0				
R21, R22, (R23)		RN16S102FK	1kΩ, 1/6W	0				
R24, R26, (R28)		ERX2SJR22	0.22Ω, 5W (*1)	0				
R25, R27, (R29)		-	-	Short				
R35, R36, (R37)		-	-	Short				
C01, C02, C05, C06		100MV100HC	100μF, 100V	0				
C03, C04		100MV50HC	0					
C07, C08, (C09)		DD104-63CJ030C50	3pF, 50V	0				
C10, C11, (C12)		ECQ-V1H104JZ	0.1μF, 50V	0				
C13, C14, (C15)		10MV22HC	22μF, 10V	0				
C16, C17, (C18)		50MV2R2HC	2.2μF, 50V	0				
C19, C20, (C21)		DD104-63B471K50	470pF, 50V	0				
C22, C23, (C24)		DD104-63B101K50	0					
D01, D02	(*3)	GZA15X	GZA15X VZ=15V					
D03, D04		ERC91-02SC	60V, 3A (FRD)	0				
L01, L02, (L03)		-	3μΗ	0				
Stand-by Control Circuit	Tr1	2SC3332 (Reference)	V <sub>CE</sub> ≥80V, I <sub>C</sub> ≥10mA	0				
	D05	GMB01 (Reference)	Di	0				
	R30	RN16S272FK	2.7kΩ, 1/6W	0				
	R32	RN16S102FK	1kΩ, 1/6W	0				
	R33	RN16S333FK	33kΩ, 1/6W	0				
	R34	RN16S202FK	2kΩ, 1/6W	0				
	C25	10MV47HC	47μF, 10V	0				
J01, 02, J03, J04, J05, J06		-	-	0				

<sup>(\*1)</sup> Metal Plate Cement Resistor use.

<sup>(\*2)</sup> STK415series (2ch Amp) doesn't mount parts of ( )

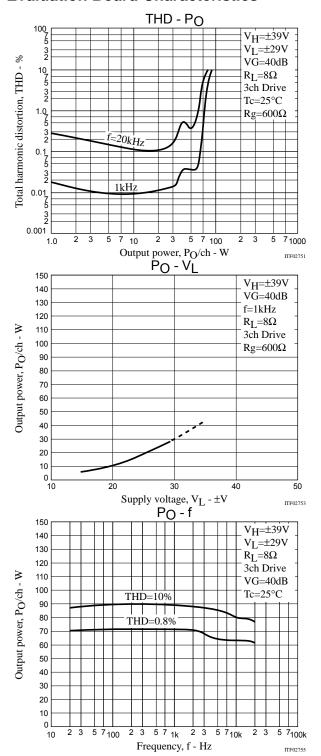
<sup>(\*3)</sup> STK415-140-E uses GZA18X (ZD=18X) for D01, D02.

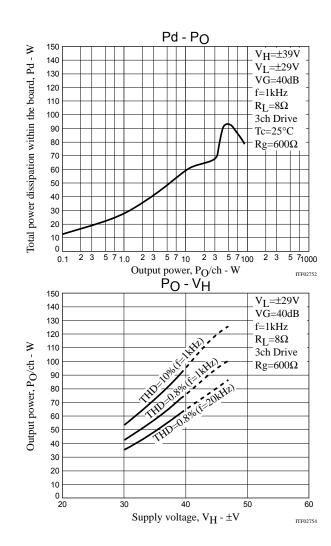
# **Pin Assignments**

[STK433-000/-100/-200 Sr & STK415/416-100 Sr Pin Layout]

[31K433-000/-100/-200 Sf &	OIIV.	+13/	410	100	) (3)	1 111	цау	Out,															
2ch class AD					1	2	3	4	5	6	7	8	9	10	11	12	13	14	15				
2ch class-AB										2cł	clas	sAB/	2.00r	nm									
STK433-030-E 30W/JEITA					-	-	+	0	0	0	0	+			1	N	S	N	1				
STK433-040-E 40W/JEITA					Р	٧	٧	U	U	U	U	Р	S	G	N	F	Т	F	N				
STK433-060-E 50W/JEITA					R	С	С	Т	Т	Т	Т	R	U	N	1	1	Α	/	1				
STK433-070-E 60W/JEITA					Е	С	С	/	/	/	1	Е	В	D	С	С	N	С	С				
								С	С	С	С		•		Н	Н	D	Н	Н				
STK433-090-E 80W/JEITA								Н	Н	Н	Н		G		1	1	lı	2	2				
STK433-100-E 100W/JEITA								1	1	2	2		N				В						
STK433-120-E 120W/JEITA								+	-	+	-		D				Υ						
STK433-130-E 150W/JEITA																							
					1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19
3ch class-AB						l	l	l		3cł	ı clas	sAB/	2.00r	nm		l	l		l				
STK433-240A-E 40W/JEITA					T _	_	+	0	0	0	0	+			1	N	s	N	П	1	N	0	0
STK433-260A-E 50W/JEITA					P	V	v	U	U	U	U	P	s	G	N	F	T	F	N	N	F	U	U
STK433-270-E 60W/JEITA					R	C	c	Т	Т	Т	Т	R	U	N	/	',	A	,	/	/	/	T	T
011(400 270 E 00W/8E117(					E	С	С	,	,	,	,	E	В	D	C	C	N	C	C	C	C	,	,
STK433-290-E 80W/JEITA					_			C	C	C	c	-	•		Н	Н	D	Н	Н	Н	Н	C	C
STK433-300-E 100W/JEITA								Н	Н	Н	Н		G		1	1		2	2	3	3	Н	Н
STK433-320-E 120W/JEITA								1	1	2	2		N		•	l	В	_	_	0		3	3
STK433-330-E 150W/JEITA								<u>'</u>	<u>'</u>	+	_		D				Y					+	_
011(100 000 E 100W/0E1//(																							
	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19				
2ch class-H		.   -   -   -   -   -   -						20	h cla:	ssH/2	2.00m	nm		l	l		l						
STK415-090-E 80W/JEITA	+	_	+	_	_	_	+	0	0	0	0	+			1	N	s	N	ı				
STK415-100-E 90W/JEITA	V	V	0	0	Р	V	V	U	U	U	U	P	s	G	N	F	Т	F	N.				
STK415-120-E 120W/JEITA	ΙĹ	Ĺ	F	F	R	Н	Н	Т	Т	Т	T	R	U	N	/	,	A	,	/				
STK415-130-E 150W/JEITA			F	F	E			,	1	,	,	E	В	D	С	C	N	C	C				
STK415-140-E 180W/JEITA			s	s	_			C	C	C	C	_	•		Н	Н	D	Н	Н				
0.11.10 1.10 2 10011102.1111			E	E				Н	Н	Н	Н		G		1	1	ī	2	2				
			T	T				1	1	2	2		N			·	В	_	_				
				-				+	_	+	_		D				Y						
	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22	23
3ch class-H	-	<u> </u>		<u> </u>			<u> </u>			30	h cla	seH/2	2.00m	nm			<u> </u>						
STK416-100-E 90W/JEITA	+		+	Ι.		Ι.	+	0	0	0	0	+			1	N	s	N	П	1	N	0	0
STK416-120-E 120W/JEITA	V	V	0	0	- Р	V	V	U	U	u	U	P	s	G	N	F	T	F	N	N	F	U	U
STK416-130-E 150W/JEITA	ľ	L	F	F	R	Н	H	Т	T	T	T	R	U	N	/ /	/	A	/	/ /	/ /	/	T	T
311410-130-L 130W/JEITA	-	-	F	F	E	'7	'7	,	/	,	/	E	В	D	C	C	N	C	C	C	C	/	
			S	S	=			C	C	C	c	=	•	ט	Н	Н	D	Н	Н	Н	Н	C	C
			E	S E				Н	Н	Н	Н		G		1	1	١	2	2	3	3		
			T	T				1	1	2	2		N		'	'	B	-	_	J	J	H 3	H 3
			'	'				<u>'</u>	'	+	_		D				Y					ە +	٦
								+	-	+	-		U				Ť						

# **Evaluation Board Characteristics**





# **Discontinued**

#### STK416-100-E

[Thermal Design Example for STK416-100-E ( $R_L = 8\Omega$ )]

The thermal resistance,  $\theta$ c-a, of the heat sink for total power dissipation, Pd, within the hybrid IC is determined as follows

Condition 1: The hybrid IC substrate temperature, Tc, must not exceed 125°C.

$$Pd \times \theta c - a + Ta < 125^{\circ}C \qquad (1)$$

Ta: Guaranteed ambient temperature for the end product

Condition 2: The junction temperature, Tj, of each power transistor must not exceed 150°C.

$$Pd \times \theta c-a + Pd/N \times \theta j-c + Ta < 150^{\circ}C \qquad (2)$$

N: Number of power transistors

θj-c: Thermal resistance per power transistor

However, the power dissipation, Pd, for the power transistors shall be allocated equally among the number of power transistors.

The following inequalities result from solving equations (1) and (2) for  $\theta$ c-a.

Values that satisfy these two inequalities at the same time represent the required heat sink thermal resistance.

When the following specifications have been stipulated, the required heat sink thermal resistance can be determined from formulas (1)' and (2)'.

Supply voltage
 Load resistance
 Guaranteed ambient temperature
 Ta

#### [Example]

When the IC supply voltage,  $V_H$ =±39V,  $V_L$ =±29V and  $R_L$  is  $8\Omega$ , the total power dissipation, Pd, within the hybrid IC, will be a maximum of 93W at 1kHz for a continuous sine wave signal according to the Pd-Po characteristics. For the music signals normally handled by audio amplifiers, a value of 1/8Po max is generally used for Pd as an estimate of the power dissipation based on the type of continuous signal. (Note that the factor used may differ depending on the safety standard used.)

This is:

Pd 
$$\approx 55.0$$
W (when 1/8PO max. = 7.5W, PO max. = 60W).

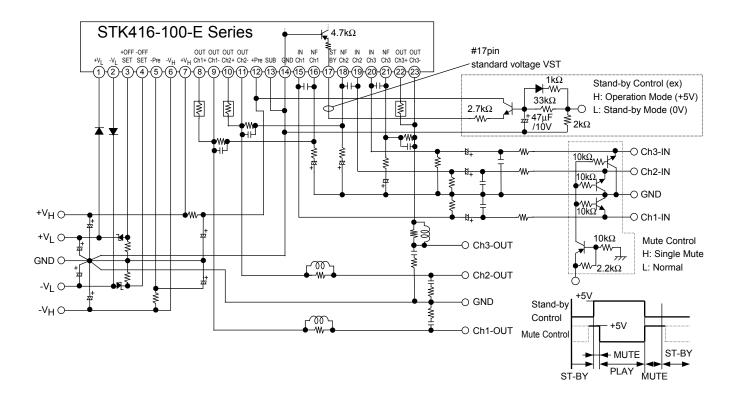
The number of power transistors in audio amplifier block of these hybrid ICs, N, is 6, and the thermal resistance per transistor,  $\theta$ j-c, is 1.8°C/W. Therefore, the required heat sink thermal resistance for a guaranteed ambient temperature, Ta, of 50°C will be as follows.

From formula (1)' 
$$\theta c\text{-a} < (125-50)/55.0 \\ < 1.36$$
 From formula (2)' 
$$\theta c\text{-a} < (150-50)/55.0 - 1.8/6 \\ < 1.52$$

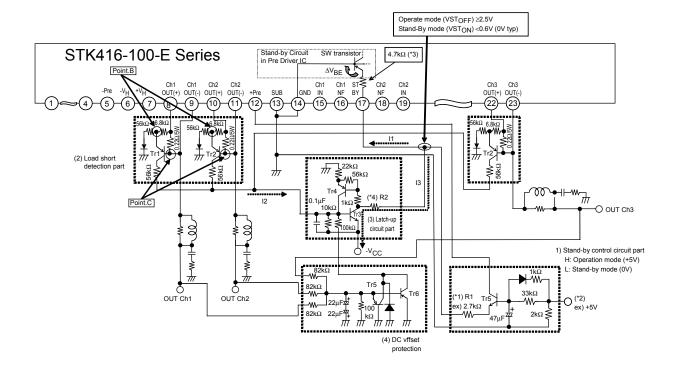
Therefore, the value of 1.36°C/W, which satisfies both of these formulae, is the required thermal resistance of the heat sink.

Note that this thermal design example assumes the use of a constant-voltage power supply, and is therefore not a verified design for any particular user's end product.

# STK416-100-E Series Stand-by Control & Mute Control Application



# STK416-100-E Series Application explanation



A protection application circuit of STK416-100sr consists of each block of (1)-(4).

- (1)Stand-by control circuit part
- (2)Load short detection part
- (3)Latch-up circuit part
- (4)DC voltage protection part

#### 1) Stand-by control circuit part

About #17 pin reference voltage VST.

#### <1> Operation mode

The SW transistor of pre-driver IC is turned on at  $VST \ge 2.5V$ , and the amplifier becomes operation mode.

ex) at VST 
$$(min) = 2.5V$$

$$VST = (*2) \times IST + 0.6V \rightarrow 2.5V = 4.7k\Omega \times IST + 0.6V, I1 \approx 0.40mA$$

#### <2> Stand-by mode

The SW transistor of pre-driver IC is turned off at VST  $\leq$  0.6V (typ 0V), and the amplifier becomes stand-by mode.

ex) at 
$$VST = 0.6V$$

$$VST = (*2) \times IST + 0.6V \rightarrow 0.6V = 4.7k\Omega \times IST + 0.6V$$
,  $I1 \approx 0mA$ 

#### (\*1) Resistance for restriction

Please set R1 for the voltage (VST) of the stand-by terminal to become ratings (+2.5V to 5.5V (typ 3.0V)).

- (\*2) Please supply the stand-by control voltage by the microcomputer etc.
- (\*3) The limitation resistance is built into hybrid IC internal (#17pin) and  $4.7k\Omega$  is built into.

#### 2) Load short detection part

TR1 (or TR2) doesn't move by normal operation. Because, Point.B - Point.C < 0.6V.

Therefore load short detection part doesn't operate.

But, when a load short-circuited, TR1 (or TR2) operate (Point.B - Point.C > 0.6V), and an electric current '12' flows.

#### 3) Latch-up circuit part

When I2 was supplied to latch-up circuit, TR3 operate.

VST becomes stand-by mode (0V) when TR3 operates (I3 flows), the power amplifier is protected.

Stand-by mode is maintained when once TR3 operates because TR3 and TR4 compose the thyristor.

It is necessary to make the Stand-by control voltage (\*2) L (0V) once to release stand-by mode and to make the power amplifier operate again.

After, when stand-by control (\*2) is returned to H (ex, +5V), it operates again.

(\*4) I3 is changed depending on the power-supply voltage (-VCC).

Please set resistance (R2) to become I1 < I3 by the following calculation types.

$$I1 \le I3 = V_{CC}/R2$$

#### 4) DC offset protection part

DC offset protection works at applying VDC (+), VDC (-)  $\approx 0.5$ V (typ) to 'OUT CH1' or 'OUT Ch2', 'OUT Ch3', then HIC will shutdown (stand-by mode).

It is necessary to make the stand-by control voltage (\*2) L (0V) once to release stand-by mode.

The power amplifier operates again after stand-by control (\*2) return to H (ex, +5V).

Please set the protection level by the resistance of '82k $\Omega$ '.

Moreover, please set the time constant by  $(22\mu)/(22\mu)$  so as not to mis-detect it when the audio signal is output.

- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co.,Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of April 2010. Specifications and information herein are subject to change without notice.